MMSZxxxT1G Series, SZMMSZxxxT1G Series

Zener Voltage Regulators

500 mW SOD−123 Surface Mount

Three complete series of Zener diodes are offered in the convenient, surface mount plastic SOD−123 package. These devices provide a convenient alternative to the leadless 34−package style.

Features

- 500 mW Rating on FR−4 or FR−5 Board
- Wide Zener Reverse Voltage Range − 2.4 V to 56 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- AEC−Q101 Qualified and PPAP Capable
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- Pb−Free Packages are Available*

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic case
FINISH: Corrosion resistant finish, easily Solderable
MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES: 260°C for 10 Seconds
POLARITY: Cathode indicated by polarity band
FLAMMABILITY RATING: UL 94 V−0

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Total Power Dissipation on FR−5 Board, (Note 1) @ T_L = 75°C Derated above 75°C	P_D	500 6.7	mW mW/°C
Thermal Resistance, Junction−to−Ambient (Note 2)	$R_{\theta JA}$	340	°C/W
Thermal Resistance, Junction−to−Lead (Note 2)	$R_{\theta JL}$	150	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	−55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR−5 = 3.5 X 1.5 inches.
2. Thermal Resistance measurement obtained via infrared Scan Method.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor®

http://onsemi.com

SOD−123
CASE 425
STYLE 1

MARKING DIAGRAM

xx = Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MMSZxxxT1G	SOD−123 (Pb−Free)	3,000 / Tape & Reel
SZMMSZxxxT1G	SOD−123 (Pb−Free)	3,000 / Tape & Reel
MMSZxxxT3G	SOD−123 (Pb−Free)	10,000 / Tape & Reel
SZMMSZxxxT3G	SOD−123 (Pb−Free)	10,000 / Tape & Reel

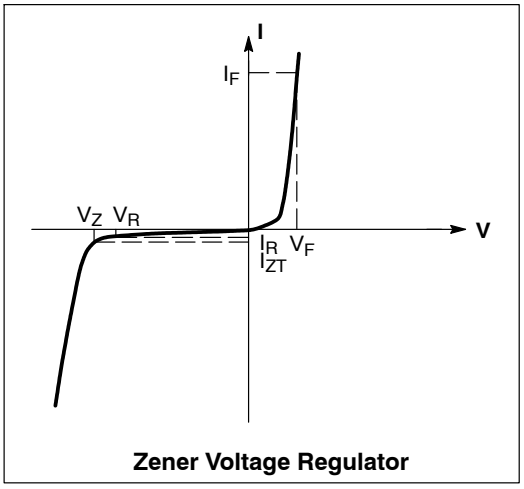
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.95 V Max. @ I_F = 10 mA)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F



Zener Voltage Regulator

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA)

Device*	Device Marking	V_{Z1} (Volts) (Notes 3 and 4) @ I_{ZT1} = 5 mA			Z_{ZT1} (Note 5)	V_{Z2} (Volts) (Notes 3 and 4) @ I_{ZT2} = 1 mA		Z_{ZT2} (Note 5)	Max Reverse Leakage Current I_R @ V_R	
		Min	Nom	Max	Ω	Min	Max	Ω	μA	Volts
MMSZ2V4T1G	T1	2.28	2.4	2.52	100	1.7	2.1	600	50	1
MMSZ2V7T1G	T2	2.57	2.7	2.84	100	1.9	2.4	600	20	1
MMSZ3V0T1G	T3	2.85	3.0	3.15	95	2.1	2.7	600	10	1
MMSZ3V3T1G	T4	3.14	3.3	3.47	95	2.3	2.9	600	5	1
MMSZ3V6T1G	T5	3.42	3.6	3.78	90	2.7	3.3	600	5	1
MMSZ3V9T1G	U1	3.71	3.9	4.10	90	2.9	3.5	600	3	1
MMSZ4V3T1G	U2	4.09	4.3	4.52	90	3.3	4.0	600	3	1
MMSZ4V7T1G	U3	4.47	4.7	4.94	80	3.7	4.7	500	3	2
MMSZ5V1T1G	***U4***	***4.85***	***5.1***	***5.36***	***60***	***4.2***	***5.3***	***480***	***2***	***2***
MMSZ5V6T1G/T3G	***U5***	***5.32***	***5.6***	***5.88***	***40***	***4.8***	***6.0***	***400***	***1***	***2***
MMSZ6V2T1G	***V1***	***5.89***	***6.2***	***6.51***	***10***	***5.6***	***6.6***	***150***	***3***	***4***
MMSZ6V8T1G	V2	6.46	6.8	7.14	15	6.3	7.2	80	2	4
MMSZ7V5T1G	V3	7.13	7.5	7.88	15	6.9	7.9	80	1	5
MMSZ8V2T1G	V4	7.79	8.2	8.61	15	7.6	8.7	80	0.7	5
MMSZ9V1T1G	V5	8.65	9.1	9.56	15	8.4	9.6	100	0.5	6
MMSZ10T1G	A1	9.50	10	10.50	20	9.3	10.6	150	0.2	7
MMSZ11T1G	A2	10.45	11	11.55	20	10.2	11.6	150	0.1	8
MMSZ12T1G	A3	11.40	12	12.60	25	11.2	12.7	150	0.1	8
MMSZ13T1G	A4	12.35	13	13.65	30	12.3	14.0	170	0.1	8
MMSZ15T1G	A5	14.25	15	15.75	30	13.7	15.5	200	0.05	10.5
MMSZ16T1G	X1	15.20	16	16.80	40	15.2	17.0	200	0.05	11.2
MMSZ18T1G/T3G	***X2***	***17.10***	***18***	***18.90***	***45***	***16.7***	***19.0***	***225***	***0.05***	***12.6***
MMSZ20T1G	X3	19.00	20	21.00	55	18.7	21.1	225	0.05	14
MMSZ22T1G	X4	20.90	22	23.10	55	20.7	23.2	250	0.05	15.4
MMSZ24T1G	X5	22.80	24	25.20	70	22.7	25.5	250	0.05	16.8

3. The type numbers shown have a standard tolerance of ±5% on the nominal Zener Voltage.
4. Tolerance and Voltage Designation: Zener Voltage (V_Z) is measured with the Zener Current applied for PW = 1 ms.
5. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for $I_{Z(AC)}$ = 0.1 $I_{Z(DC)}$, with the AC frequency = 1 kHz.

*Include SZ-prefix devices where applicable.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA)

Device*	Device Marking	V_{Z1} (Volts) (Notes 6 and 7) @ I_{ZT1} = 2 mA			Z_{ZT1} (Note 8)	V_{Z2} (Volts) (Notes 6 and 7) @ I_{ZT2} = 0.1 mA		Z_{ZT2} (Note 8) @ I_{ZT2} = 0.5 mA	Max Reverse Leakage Current I_R @ V_R	
		Min	Nom	Max	Ω	Min	Max	Ω	μA	Volts
MMSZ27T1G/T3G	Y1	25.65	27	28.35	80	25	28.9	300	0.05	18.9
MMSZ30T1G	Y2	28.50	30	31.50	80	27.8	32	300	0.05	21
MMSZ33T1G	Y3	31.35	33	34.65	80	30.8	35	325	0.05	23.1
MMSZ36T1G	Y4	34.20	36	37.80	90	33.8	38	350	0.05	25.2
MMSZ39T1G	Y5	37.05	39	40.95	130	36.7	41	350	0.05	27.3
MMSZ43T1G	Z1	40.85	43	45.15	150	39.7	46	375	0.05	30.1
MMSZ47T1G	Z2	44.65	47	49.35	170	43.7	50	375	0.05	32.9
MMSZ51T1G	Z3	48.45	51	53.55	180	47.6	54	400	0.05	35.7
MMSZ56T1G	Z4	53.20	56	58.80	200	51.5	60	425	0.05	39.2

6. The type numbers shown have a standard tolerance of ±5% on the nominal Zener Voltage.
7. Tolerance and Voltage Designation: Zener Voltage (V_Z) is measured with the Zener Current applied for PW = 1 ms.
8. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for $I_{Z(AC)}$ = 0.1 $I_{Z(DC)}$, with the AC frequency = 1 kHz.

*Include SZ-prefix devices where applicable.

TYPICAL CHARACTERISTICS

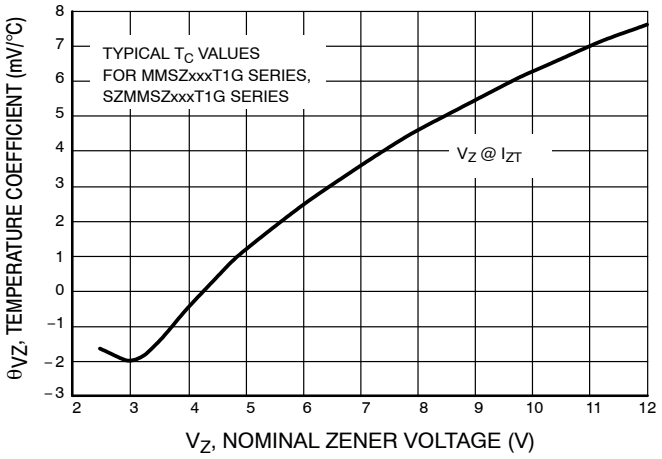


Figure 1. Temperature Coefficients (Temperature Range −55°C to +150°C)

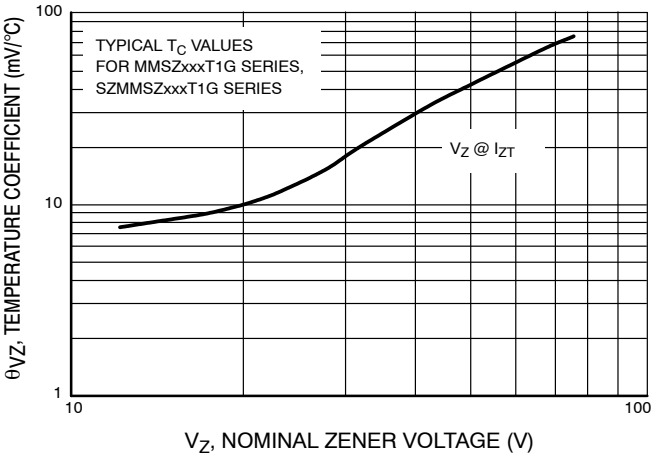


Figure 2. Temperature Coefficients (Temperature Range −55°C to +150°C)

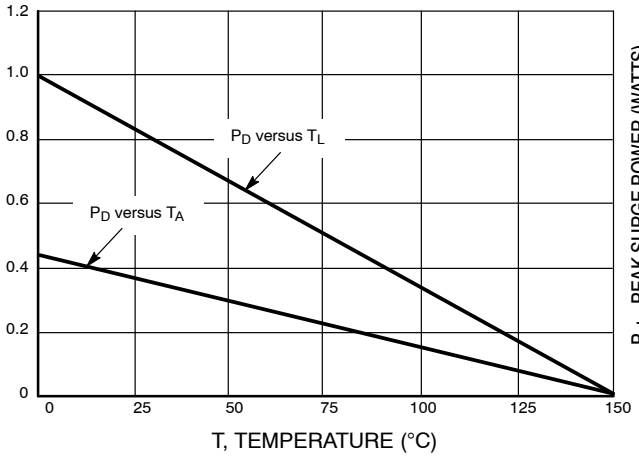


Figure 3. Steady State Power Derating

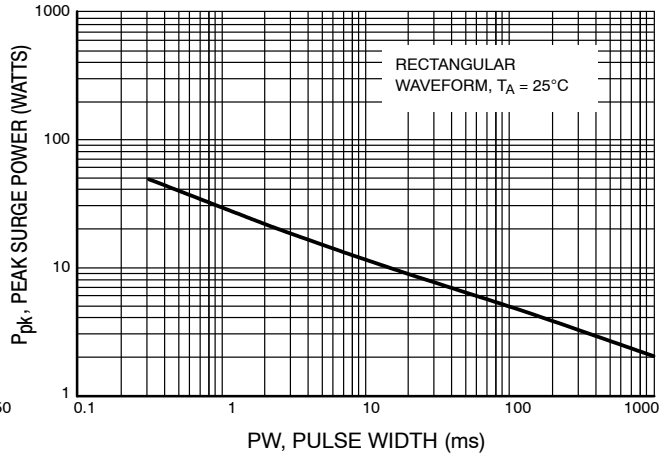


Figure 4. Maximum Nonrepetitive Surge Power

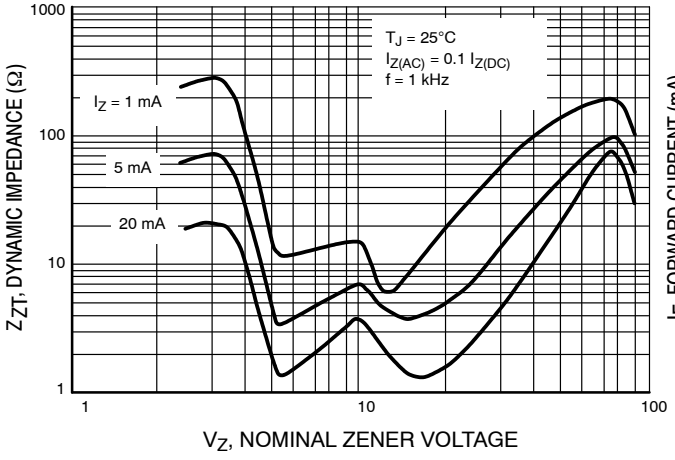


Figure 5. Effect of Zener Voltage on Zener Impedance

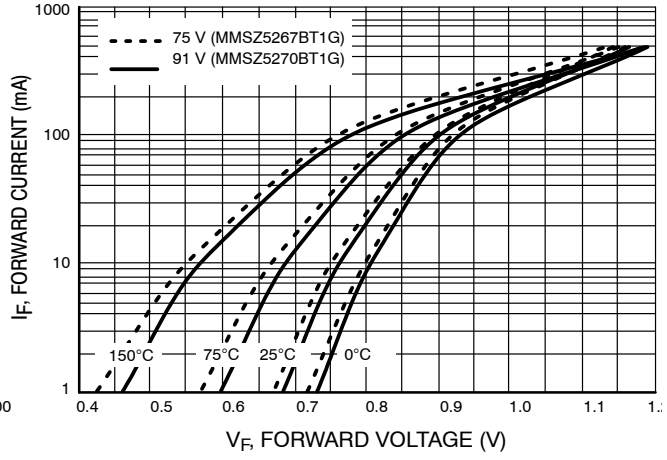


Figure 6. Typical Forward Voltage

TYPICAL CHARACTERISTICS

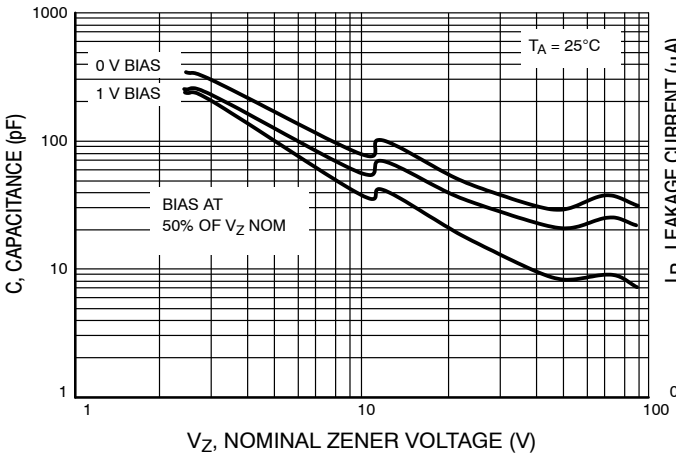


Figure 7. Typical Capacitance

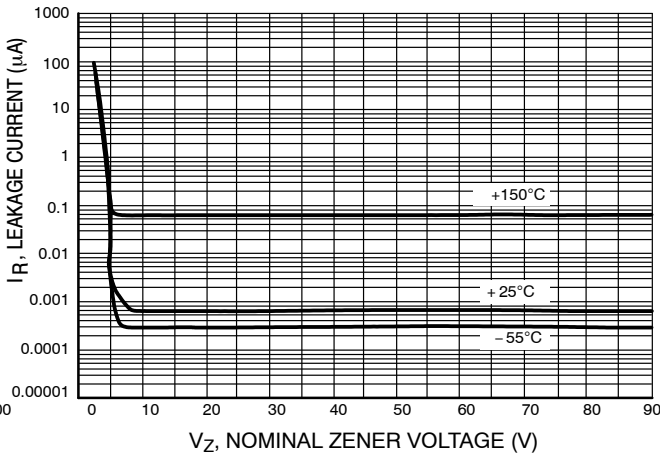


Figure 8. Typical Leakage Current

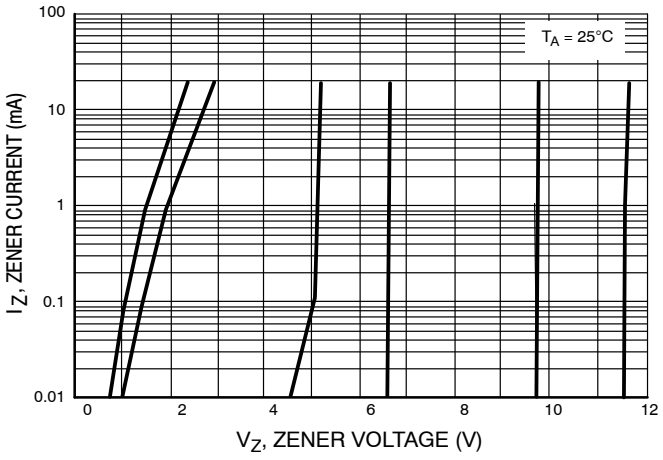


Figure 9. Zener Voltage versus Zener Current (V_Z Up to 12 V)

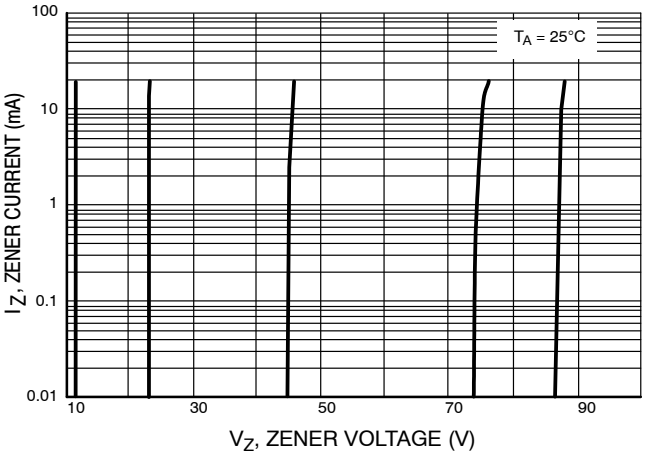
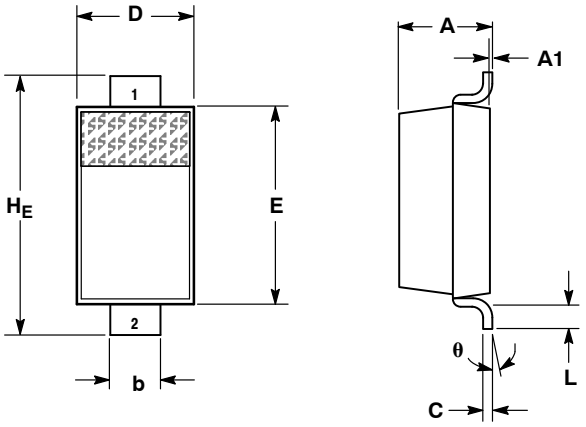


Figure 10. Zener Voltage versus Zener Current (12 V to 91 V)

PACKAGE DIMENSIONS

SOD−123
CASE 425−04
ISSUE G

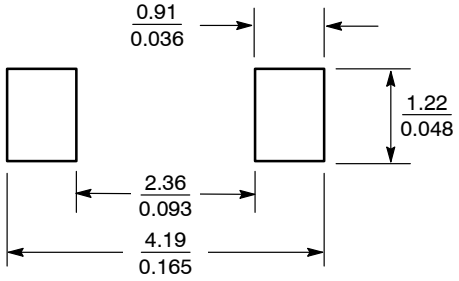


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
c	---	---	0.15	---	---	0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
E	2.54	2.69	2.84	0.100	0.106	0.112
H_E	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25	---	---	0.010	---	---
θ	0°	---	10°	0°	---	10°

STYLE 1:
PIN 1. CATHODE
2. ANODE

SOLDERING FOOTPRINT*



SCALE 10:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

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Literature Distribution Center for ON Semiconductor
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Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
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Телефон: +7 812 627 14 35

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